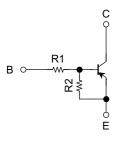
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN2901FE, RN2902FE, RN2903FE RN2904FE, RN2905FE, RN2906FE

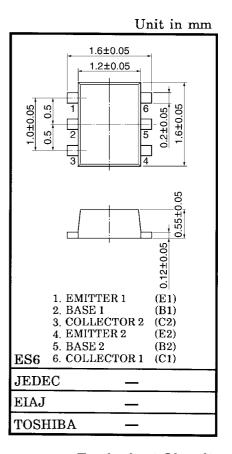
Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

- Two devices are incorporated into an Extreme-Super-Mini (6 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
 Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Complementary to RN1901FE~RN1906FE

Equivalent Circuit and Bias Resistor Values



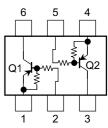
Type No.	R1 (kΩ)	R2 (kΩ)
RN2901FE	4.7	4.7
RN2902FE	10	10
RN2903FE	22	22
RN2904FE	47	47
RN2905FE	2.2	47
RN2906FE	4.7	47



Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage	RN2901FE~RN2906FE	V_{CBO}	-50	V	
Collector-emitter voltage	KINZ90 II E-KINZ900I E	V_{CEO}	-50	V	
Emitter-base voltage	RN2901FE~RN2904FE	\/	-10	V	
	RN2905FE, RN2906FE	V _{EBO}	-5		
Collector current		Ic	-100	mA	
Collector power dissipation	RN2901FE~RN2906FE	P _C (Note)	100	mW	
Junction temperature	KINZ90 IFE~KINZ900FE	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Equivalent Circuit (top view)



Note: Total rating

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TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general
can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the
buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and
to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or
damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.

• The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.



Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2901FE~2906FE	I _{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-100	nA
		I _{CEO}	$V_{CE} = -50 \text{ V}, I_B = 0$	_	_	-500	IIA
Emitter cut-off current	RN2901FE	- I _{EBO}	$V_{EB} = -10 \text{ V, } I_{C} = 0$	-0.82	_	-1.52	mA
	RN2902FE			-0.38	_	-0.71	
	RN2903FE			-0.17	_	-0.33	
	RN2904FE			-0.082	_	-0.15	
	RN2905FE			-0.078	_	-0.145	
	RN2906FE		$V_{EB} = -5 \text{ V}, I_{C} = 0$	-0.074	_	-0.138	
	RN2901FE		V _{CE} = -5 V, I _C = -10 mA	30	_	_	
	RN2902FE			50	_	_	
DO	RN2903FE	1 .		70	_	_	
DC current gain	RN2904FE	- h _{FE}		80	_	_	
	RN2905FE			80	_	_	
	RN2906FE			80	_	_	
Collector-emitter saturation voltage	RN2901FE~2906FE	V _{CE (sat)}	$I_C = -5 \text{ mA},$ $I_B = -0.25 \text{ mA}$	_	-0.1	-0.3	٧
	RN2901FE		$V_{CE} = -0.2 \text{ V},$ $I_{C} = -5 \text{ mA}$	-1.1	_	-2.0	V
	RN2902FE	VI (ON)		-1.2	_	-2.4	
	RN2903FE			-1.3	_	-3.0	
Input voltage (ON)	RN2904FE			-1.5	_	-5.0	
	RN2905FE			-0.6	_	-1.1	
	RN2906FE			-0.7	_	-1.3	
land with a (OFF)	RN2901FE~2904FE	V _{I (OFF)}	V _{CE} = -5 V, I _C = -0.1 mA	-1.0	_	-1.5	V
Input voltage (OFF)	RN2905FE, 2906FE			-0.5		-0.8	
Transition frequency	RN2901FE~2906FE	f _T	$V_{CE} = -10 \text{ V},$ $I_{C} = -5 \text{ mA}$	_	200	_	MHz
Collector output capacitance	RN2901FE~2906FE	C _{ob}	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz	_	3	6	pF
	RN2901FE		_	3.29	4.7	6.11	kΩ
	RN2902FE	- R1		7	10	13	
Input resistor	RN2903FE			15.4	22	28.6	
	RN2904FE			32.9	47	61.1	
	RN2905FE			1.54	2.2	2.86	
	RN2906FE			3.29	4.7	6.11	
Resistor ratio	RN2901FE~2904FE	R1/R2	_	0.9	1.0	1.1	
	RN2905FE			0.0421	0.0468	0.0515	
	RN2906FE	1		0.09	0.1	0.11	

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The information contained herein is subject to change without notice.

Type Name	Marking
RN2901FE	Type name
RN2902FE	Type name YB
RN2903FE	Type name
RN2904FE	Type name
RN2905FE	Type name YE
RN2906FE	Type name